

Latest updates on the Geant4 simulation of a single crystal bar

Yong Liu, Baohua Qi Sep. 9, 2020 CEPC Calorimeter Software Meeting



Overview

- Geant4 full simulation
 - Adapted from a short crystal bar (single-end readout)
 - Geometry
 - A 40cm long crystal bar, 1x1 cm² transverse size
 - Read out by two SiPMs at both ends

SiPM1 SiPM2 Muon BGO crystal

- Properties
 - BGO: light yield, decay times (fast and slow), refractive index, transmission (absorption length)
 - Assumed fast rise time
 - Wrapping: ESR foil (~99% reflectivity) with air gaps (total reflections)
 - SiPM: 6x6 mm² sensitive area, Photon Detection Efficiency (PDE), realistic SMD package
- Primary particle
 - 1GeV muon for MIP calibration
- Optical photon processes:
 - Scintillation, Cherenkov, absorption, refraction/reflection at boundaries



Overview



- Information extracted from G4
 - Energy deposition: mean ~10 MeV/MIP, determined by crystal thickness
 - #scintillation photons
 - #detected photons at either SiPM
 - Time stamp of each detected photon
 - T0: shooting of the primary particle (muon)
 - Including: scintillation time (~hundreds ns), propagation time (a few ns) within the crystal bar
 - Excluding: timing uncertainties from SiPMs and electronics
 - MC samples: 30 events per run (~90s/event)
- (Simple) Analysis on timing

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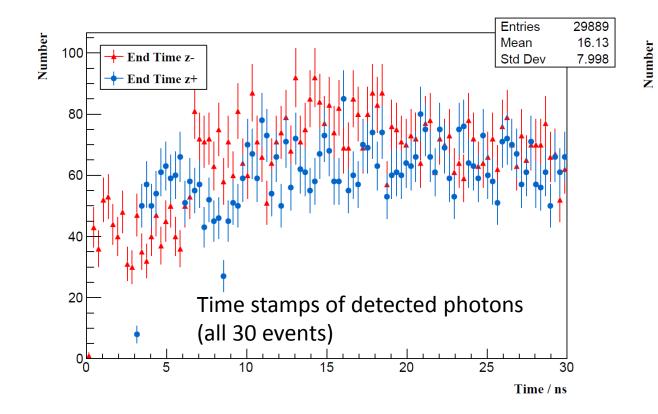
Choose the time stamp of the 1st photon detected at each SiPM

Fresh results from last few days (trying to understand better), thanks to Baohua's efforts

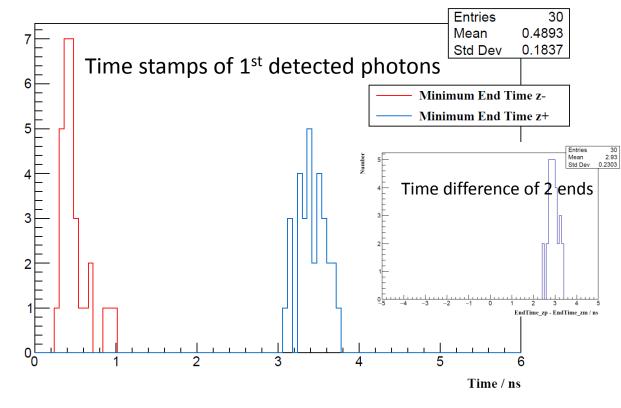


Simulation results: preliminary

- Scenario 1: close to one end
 - 1cm away from one SiPM
 - Only focus on the rising edge of signals





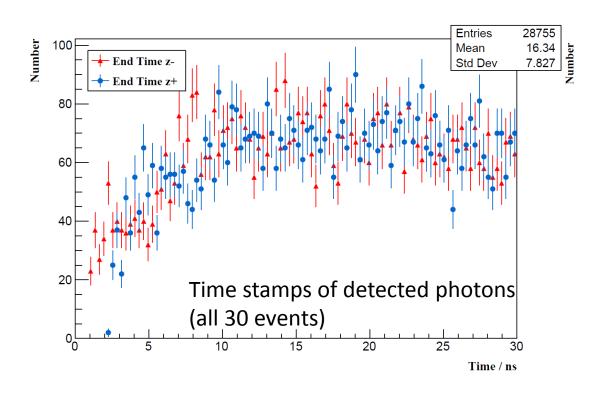


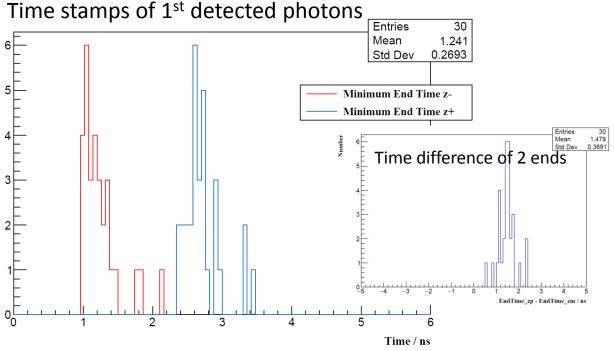


Simulation results: preliminary

- Scenario 2: in one quarter along the bar
 - 10cm away from one SiPM
 - Only focus on the rising edge of signals









Simulation results: preliminary

- Scenario 3: in the middle of the bar
 - 20cm away from one SiPM
 - Only focus on the rising edge of signals



